

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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DDTA (LO-R1) E

PNP PRE-BIASED 100 mA SURFACE MOUNT TRANSISTOR

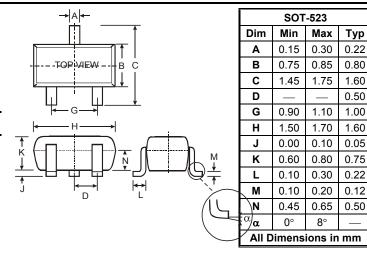
Features

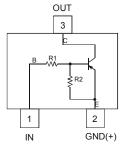
- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDTC)
- Built-In Biasing Resistors
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device (Note 3 and 4)

Mechanical Data

- Case: SOT-523
- Case Material: Molded Plastic. UL Flammability
- Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin Solderable per MIL-STD 202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe)
- Terminal Connections: See Diagram
- Marking Information: See Table Below & Page 3
- Ordering Information: See Page 3
- Weight: 0.002 grams (approximate)

P/N	R1 (NOM)	R2 (NOM)	Type Code
DDTA122LE	0.22KΩ	10KΩ	P81
DDTA142JE	0.47KΩ	10KΩ	P82
DDTA122TE	0.22 K Ω	OPEN	P83
DDTA142TE	0.47ΚΩ	OPEN	P84





Schematic and Pin Diagram

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit	
Supply Voltage, (2) to (3)		V_{CC}	-50	V	
Input Voltage, (1) to (2)	DDTA122LE DDTA142JE	V _{IN}	+5 to -6 +5 to -6	V	
Input Voltage, (2) to (1)	DDTA122TE DDTA142TE	V _{EBO} (MAX)	-5	V	
Output Current	All	Ic	-100	mA	
Power Dissipation	(Note 1)	P _d	150	mW	
Thermal Resistance, Junction to Ambient Air	(Note 1)	$R_{ hetaJA}$	625	°C/W	
Operating and Storage Temperature Range		T _j , T _{STG}	-55 to +150	°C	

Notes:

- 1. Mounted on FR4 PC Board with recommended pad layout at http://www.diodes.com/datasheets/ap02001.pdf.
- No purposefully added lead.
- 3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 4. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



Electrical Characteristics @TA = 25°C unless otherwise specified R1, R2 Types

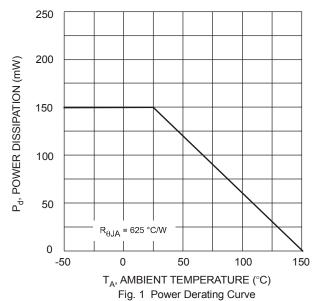
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Input Voltage	DDTA122LE DDTA142JE	V _{I(off)}	-0.3 -0.3	_	_	V	V _{CC} = -5V, I _O = -100μA
	DDTA122LE DDTA142JE			$V_O = -0.3V$, $I_O = -20mA$ $V_O = -0.3V$, $I_O = -20mA$			
Output Voltage	$V_{O(on)}$	_	_	-0.3V	V	$I_{O}/I_{I} = -5$ mA/-0.25mA	
Input Current DDTA122LE DDTA142JE		l _l	_	_	-28 -13	mA	V _I = -5V
Output Current		I _{O(off)}	_	_	-0.5	μА	V _{CC} = -50V, V _I = 0V
DC Current Gain DDTA122LE DDTA142JE		G _l	56 56	_	_	_	V _O = -5V, I _O = -10mA
Gain-Bandwidth Product*		f⊤	_	200	_	MHz	V _{CE} = -10V, I _E = -5mA, f = 100MHz

^{*} Transistor - For Reference Only

Electrical Characteristics @TA = 25°C unless otherwise specified R1-Only Types

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	BV _{CBO}	-50		_	V	$I_C = -50\mu A$	
Collector-Emitter Breakdown Voltage	BV _{CEO}	-40	_	_	V	I _C = -1mA	
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	_	_	V	I _E = -50μA I _E = -50μA	
Collector Cutoff Current	I _{CBO}	_	_	-0.5	μА	V _{CB} = -50V	
Emitter Cutoff Current DDTA122TE DDTA142TE		I _{EBO}	_		-0.5 -0.5	μА	V _{EB} = -4V
Collector-Emitter Saturation Voltage		V _{CE(sat)}	_	_	-0.3	V	I _C = -5mA, I _B = -0.25mA
DC Current Transfer Ratio DDTA122TE DDTA142TE		h _{FE}	100 100	250 250	600 600		I _C = -1mA, V _{CE} = -5V
Gain-Bandwidth Product*	f _T	_	200	_	MHz	V _{CE} = -10V, I _E = 5mA, f = 100MHz	

^{*} Transistor - For Reference Only



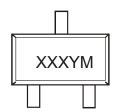


Ordering Information (Note 5)

Device	Packaging	Shipping
DDTA122LE-7-F	SOT-523	3000/Tape & Reel
DDTA142JE-7-F	SOT-523	3000/Tape & Reel
DDTA122TE-7-F	SOT-523	3000/Tape & Reel
DDTA142TE-7-F	SOT-523	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



XXX = Product Type Marking Code (See Page 1) YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year	2006	2007	2008	2009	2010	2011	2012
Code	Т	U	V	W	X	Y	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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